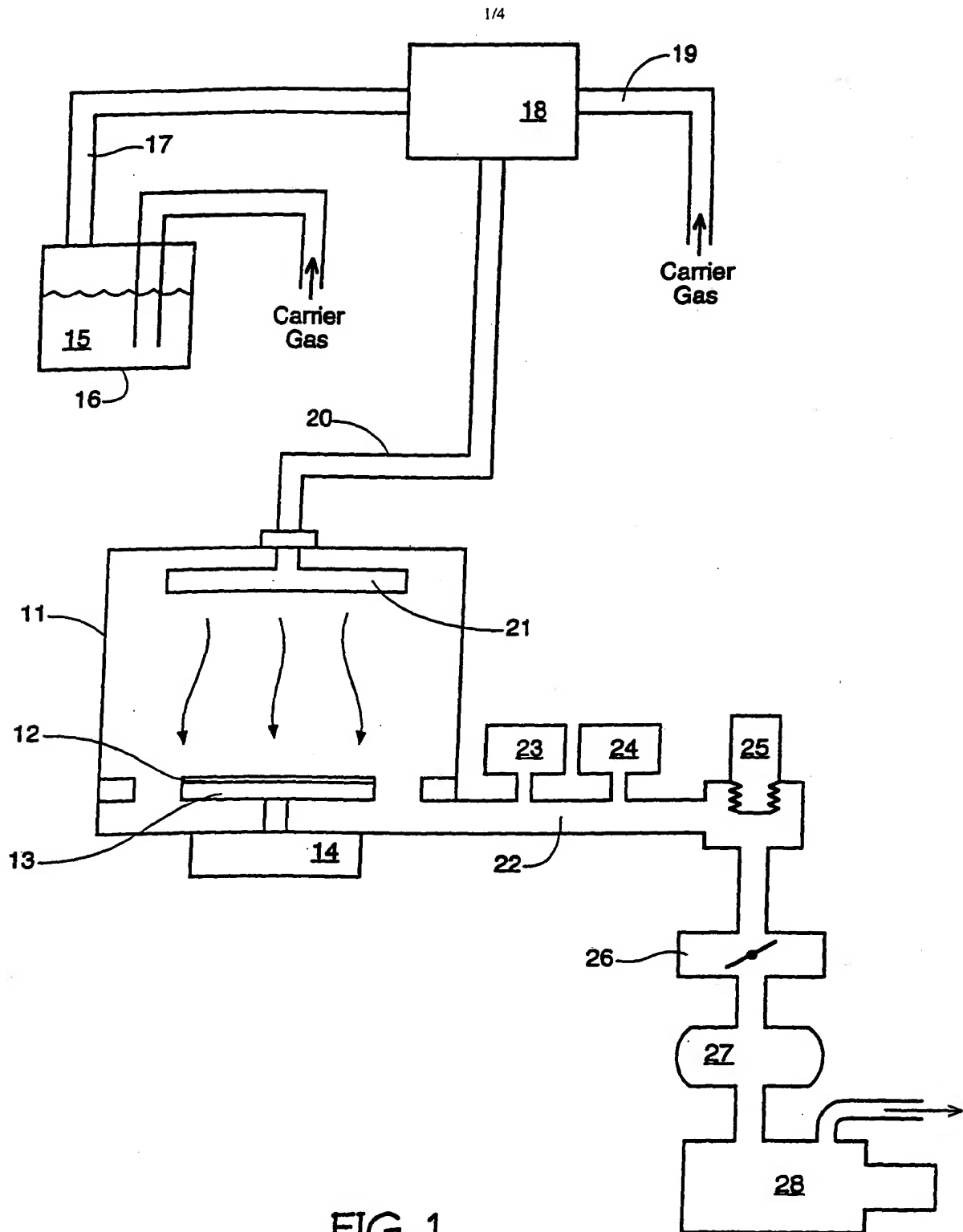


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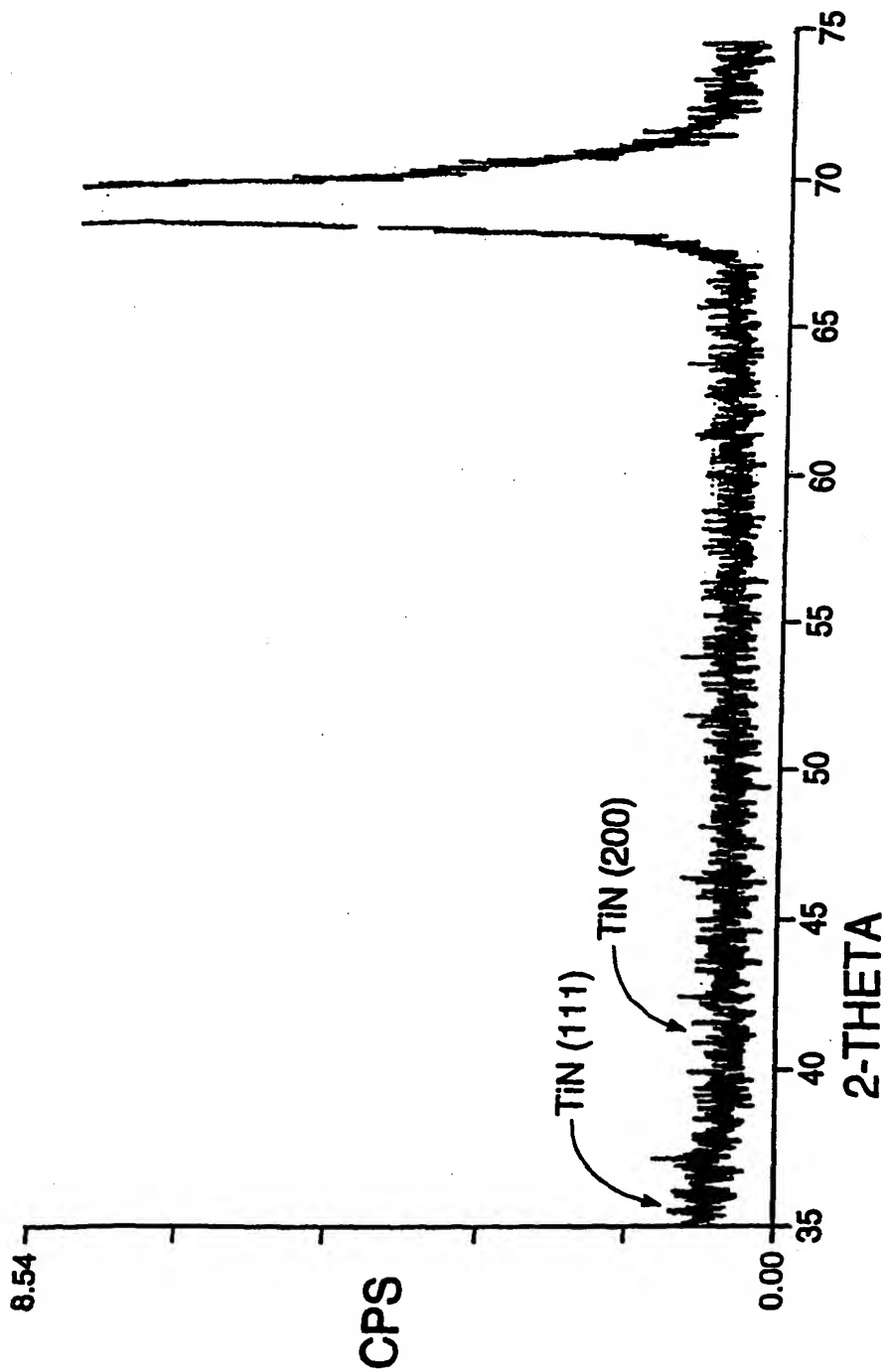
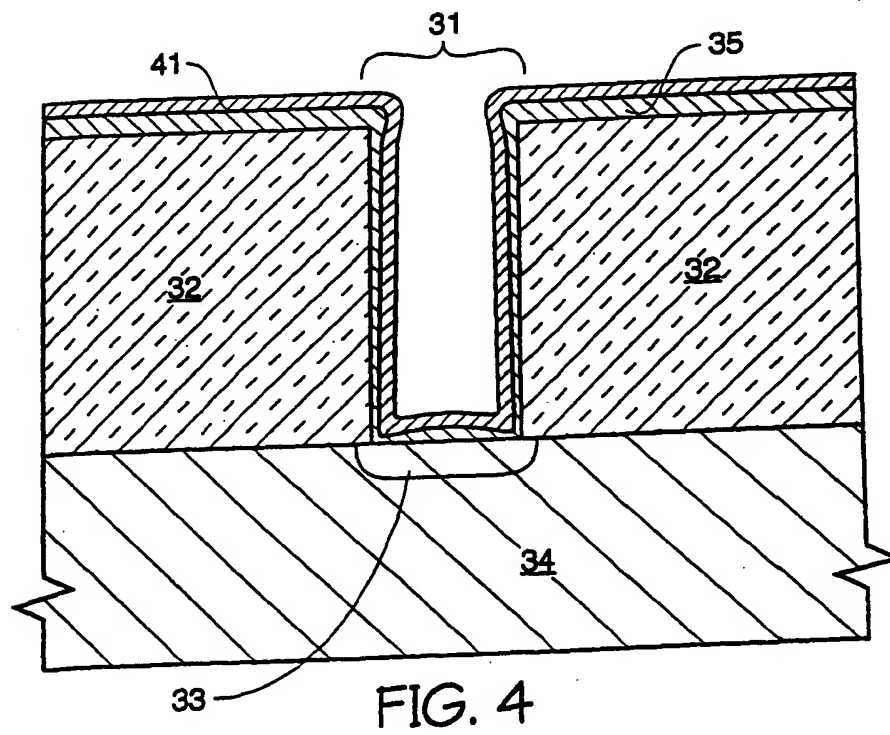
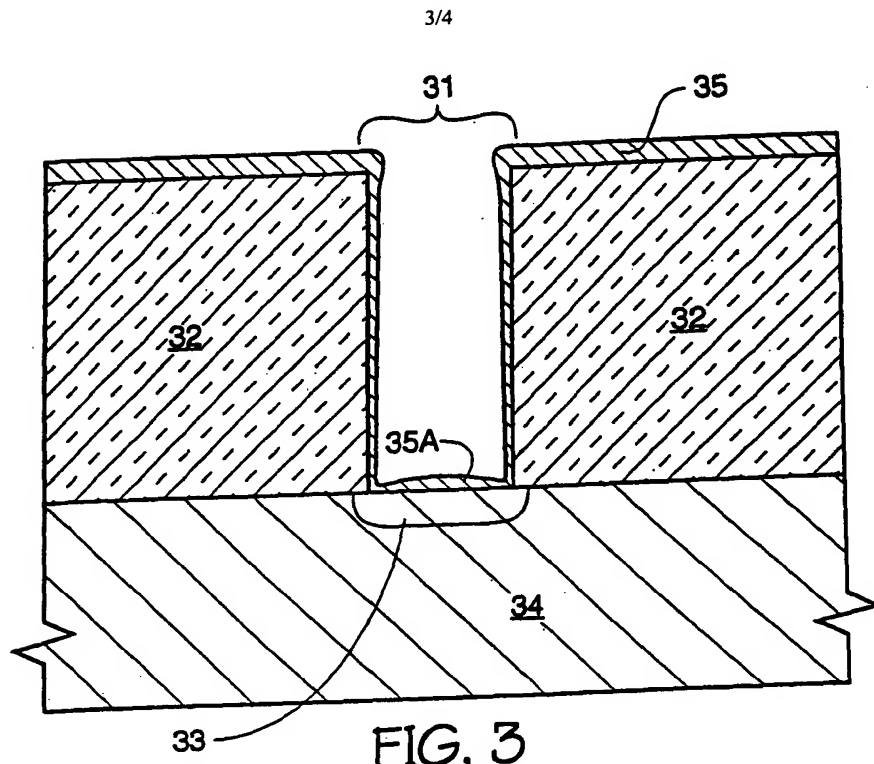


FIG. 2



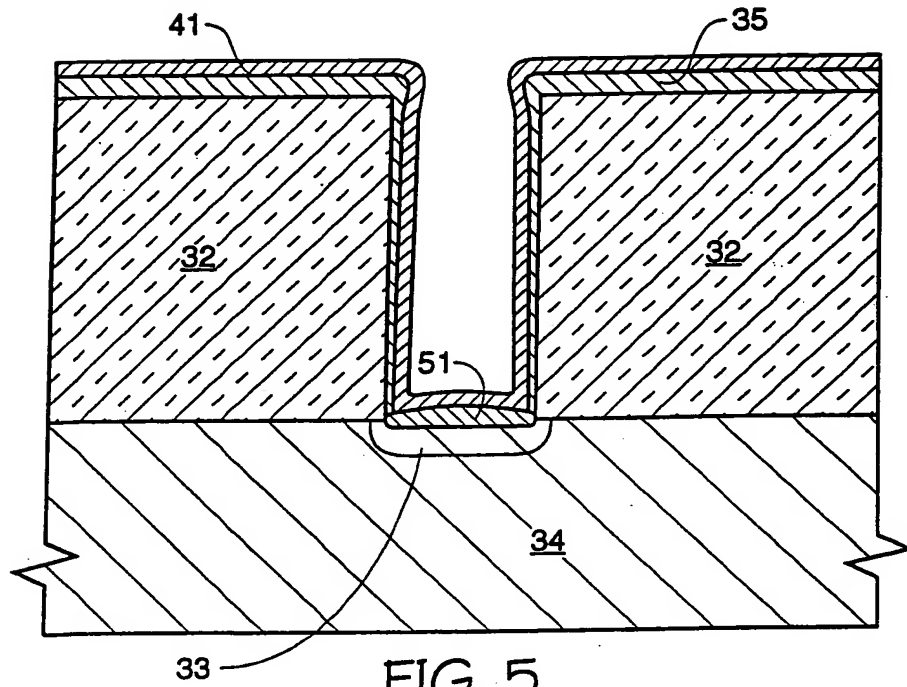


FIG. 5

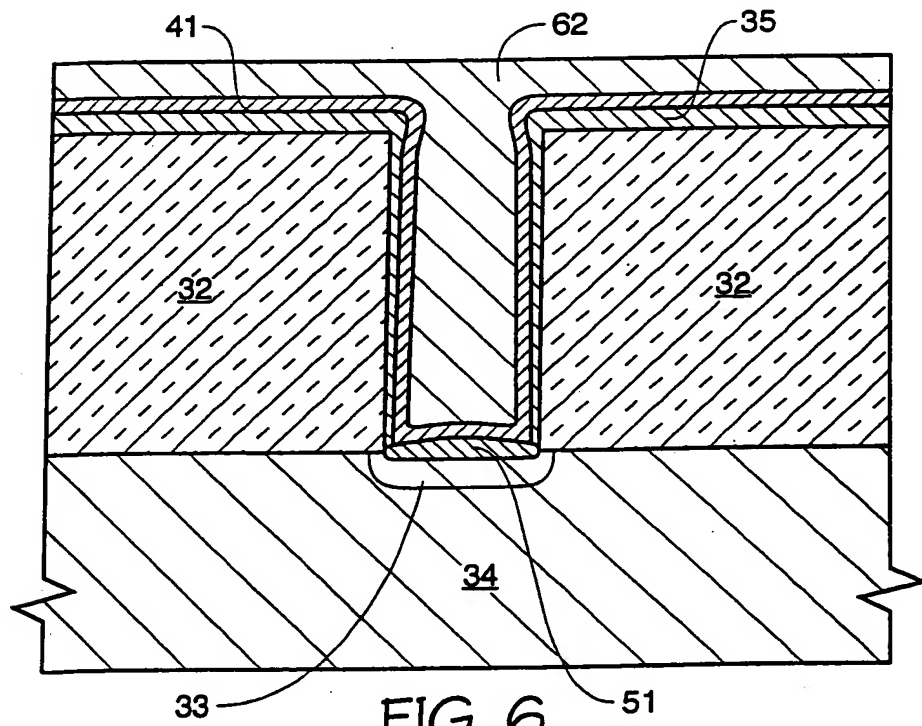


FIG. 6